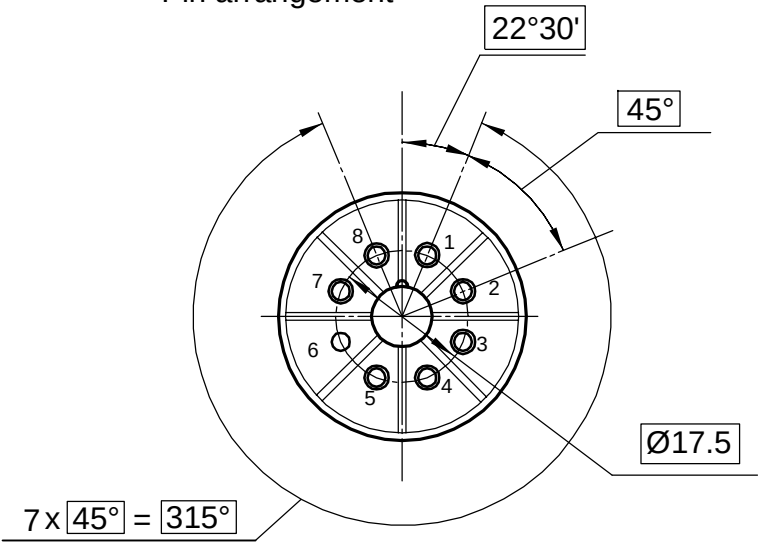
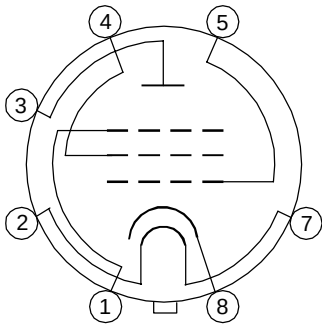


Vacuum tube EL34EH, EL34WXT is a output pentod in the glass bulb, with equipotential cathode, designed to amplify low frequency power in the output stages of HI - FI audio.

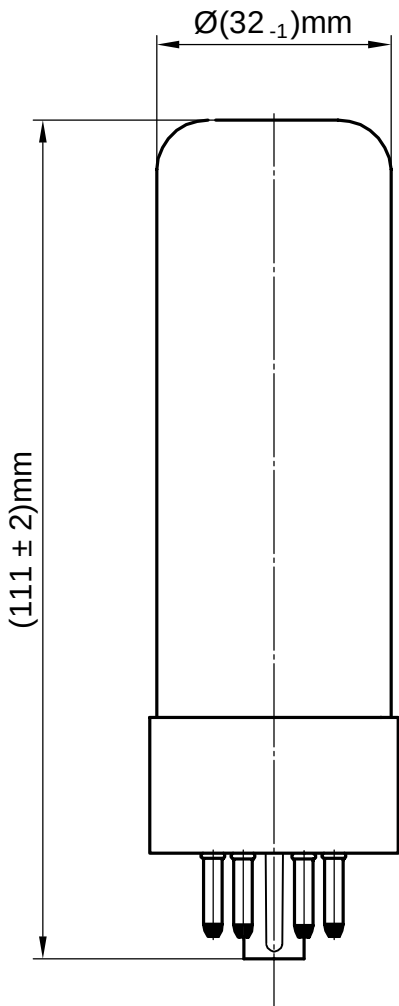
Pin arrangement



Electrode -to - lead connection diagram



Dimensions



Lead designation	Name of electrode
1	Grid 3
2, 7	Heater
3	Plate
4	Grid 2
5	Grid 1
6	No
8	Cathode

Electrical parameters

EL34EH, EL34WXT

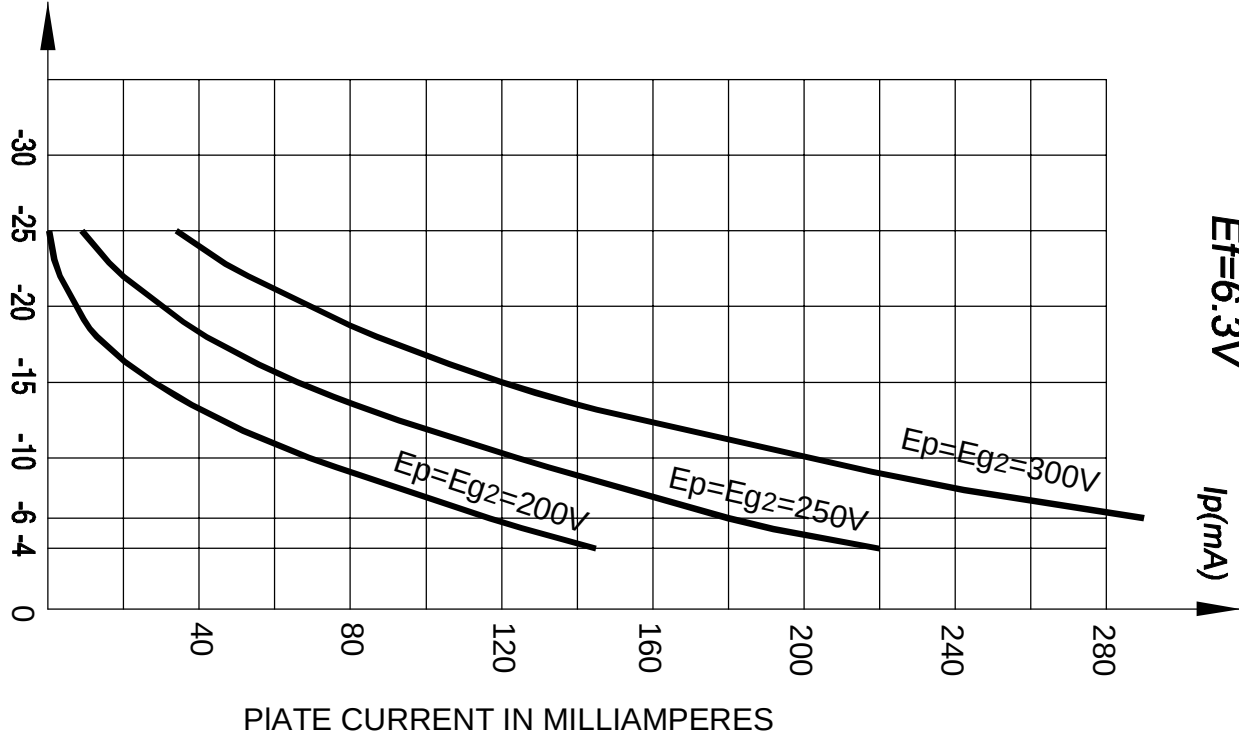
Parameters, conditions and units	Nominal	
	min	max
First grid reverse current, μA (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 13.5 V, second grid voltage 265 V, first grid circuit resistance 0.51 M Ω)	—	1.5
Heater current, A	1.35	1.65
Plate current, mA (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 13.5 V, second grid voltage 265 V)	80	120
Second grid current, mA (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 13.5 V, second grid voltage 265 V)	10	20
Output power, W (at: filament voltage 6.3 V, plate voltage 250 V, first grid voltage minus 13.5 V, second grid voltage 265 V, plate circuit resistance 2.0 k Ω , first grid alternating voltage, efficacious 8.7 V)	8.5	—
First grid cut-off voltage, negative, V (at: filament voltage 6.3 V, plate voltage 250 V, second grid voltage 265 V)	—	48
Slope of characteristic, mA/V (at: filament voltage 6.3 V, anode voltage 250 V, first grid voltage minus 13.5 V, second grid voltage 265 V)	9.5	15
Distortion factor,% (at: filament voltage 6.3 V, plate voltage 265 V, first grid voltage minus 13.5 V, second grid voltage 265 V, plate circuit resistance 2.0 k Ω , first grid alternating voltage, efficacious 8.7 V)	—	13.5
Cahtode - heater insulation resistance, M Ω (at: filament voltage 6.3 V cathode -heater voltage ± 100 V)	2	—

Operating conditions limits

Parameters, units	Nominal	
	min	max
Filament voltage, V	5.5	7.0
Cathode - heater voltage, V	—	± 100
Cathode current, mA	—	150
Power dissipation at the plate, W	—	25
Power dissipation at the second grid, W	—	8
First grid circuit resistance, M Ω fixed bias	—	0.5
self - bias	—	0.7
Temperature at the most heated part of the envelope, K°	—	523

$I_p = f(E_{g1})$

$E_f = 6.3V$



$I_p = f(E_p)$

$E_f = 6.3V, E_{g2} = 250V$

